

First-principles prediction of metastable niobium and tantalum nitrides M_4N_5 and M_5N_6 stoichiometry

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ABSTRACT

A first-principles plane-wave pseudopotential method based on the density functional theory is used to investigate the structural, elastic and electronic properties of M_4N_5 and M_5N_6 ($M =$ a transition metal (TM) Nb, Ta). C_{33} elastic constant for all compounds is found to be much larger than C_{11} , indicating that a -axis is more compressible than c -axis. Interestingly, we find that C_{33} and C_{11} are significantly larger than other elastic constants, resulting in a pronounced elastic anisotropy.

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1. Introduction

TaN_x , NbN_x transition metal nitrides are refractory metals that possess technologically useful properties including superconductivity and ultra high hardness, comparable to diamond (experimental bulk modulus = 443 GPa). Also, they combine various physical and chemical, such as high melting points (around 3000 °C). While the Ta–N and Nb–N equilibrium phase diagrams are extremely rich and relatively unexplored both experimentally and theoretically. It exhibits a remarkable richness with regard to that can form and is used, for example, in coatings for cutting tools and wear-resistant layers, as well as for thin-film resistors and diffusion barriers in integrated circuits. In addition to the equilibrium phases, a variety of metastable phases have been reported. As far as tantalum mononitride (TaN) is concerned, owing to its outstanding mechanical and chemical stability [1], it is widely used in many technological applications, for example as a hard coating material. Niobium nitrides are very interesting materials because of their high hardness [2,3], high wear resistance [4], high melting point [1], good temperature stability, good chemical stability at

high temperature [5] and superconducting properties [6]. Focusing on superconducting properties, Papaconstantopoulos et al. [7] studied V and VI groups of transition metal mononitrides, whereas on one hand Stampfl et al. [8] investigated electronic structure and physical properties of early transition metal mononitrides. On the other hand Stampfl et al. [9] studied stable and metastable structures of the multiphase tantalum nitride system, using the density functional theory (DFT) calculations and the Full-potential Linearized Augmented Plane-Wave (FLAPW) method. S. Nagao et al. [10] studied anisotropic elasticity in group IVB of transition-metal mononitrides., Chen et al. [11] investigated pressure effects on niobium nitride while Ojha et al. [12] explored pressure-induced structural phase transformations and elastic properties in transition metal mononitrides. Also, Joelsson and Hultman [13] analysed phase stability of $Nb_xZr_{1-x}N$ thin films [14]. Obtained the nitrides Ta_4N_5 and Ta_5N_6 by heating Ta_3N_5 in an atmosphere of Ar or NH_3 [15]. Observed that when thin films of Ta are evaporated in an O free NH_3 atmosphere, Ta_5N_6 forms at 1100 °C. Ta_4N_5 and Ta_5N_6 also form when Ta_3N_5 is heated in vacuum.

Here we perform first-principles density functional calculations to investigate the crystal structures and electronic characteristics of a bulk of Niobium and Tantalum nitrides M_4N_5 and M_5N_6 . Many of these nitrides can be described as close-packed metal lattices (f.c.c. or h.c.p.), with a nitrogen atom at the center of an octahedral

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structure. Hexagonal (composition, at.% N \sim 54.5 for Ta₅N₆, Pearson symbol *hP22*) M₅N₆ present an Nb₅N₆ prototype structure with a space group *P6₃/mcm*, N°193 [14–16], while tetragonal (composition, at. % N \sim 55 for Ta₄N₅, Pearson symbol *tI18*) M₄N₅ present a H₄Li₄Rh prototype structure with a space group *I4/m*, N°87 [14,15,17]. This article is organized as follows: The computational method is described in Section 2. In Section 3, the results of the calculations are presented and compared with available experimental and theoretical data. Conclusion is given in Section 4.

2. Computational method

Computer simulation techniques are becoming more and more important in understanding of physical properties of materials. Our first-principles calculations are performed within a Plane Wave Pseudo Potential (PWPP) method which has been implemented in a CASTEP (Cambridge Serial Total Energy Package) simulation program [18]. It is based on the Density Functional Theory (DFT) [19,20] which is, in principle, an exact theory of the ground state. In our calculations, using the Perdew-Burke-Ernzerhof scheme, known as PBE scheme [21], a Generalized Gradient Approximation (GGA) is made for the electronic exchange-correlation potential energy. Coulomb potential energy caused by electron-ion interaction is described within an ultrasoft scheme, in which the Nb (4d⁴ 5s¹), Ta (4f¹⁴ 5d³ 6s²), and N (2s² 2p³) orbitals are treated as valence electrons. According to an ultrasoft condition, the pseudo-wave function which is related to the pseudo potential matches the plane-wave function expanded with Kohn-Sham beyond cut-off energy. Using high cut-off energy, at the price of spending long computational time, can actually provide accurate results. The cut-off energy for the plane-wave expansion was set at 380 eV and the Brillouin zone sampling was carried out using the 6 × 6 × 6 set of Monkhorst-Pack mesh [22]. Atomic positions are relaxed and optimized with a density mixing scheme using the Conjugate Gradient (CG) method for eigenvalues minimization. The equilibrium lattice parameter is then computed from a structural

Table 1

Calculated M₄N₅ and M₅N₆ (composition, at.% N \sim 55 and 54.5 respectively) structures: lattice parameter in Å; ratio *c/a*; volumes per formula unit (f.u.) in Å³, and the space group and compared with experimental data. The notation N_{f.u.} represents the number of f.u. in the unit cell.

Space group	<i>a</i>	<i>c</i>	<i>c/a</i>	<i>V</i>	N _{f.u.}
<i>Tetragonal prototypes</i>					
Nb ₄ N ₅ <i>I4/m</i>	7.254	4.557	0.628	239.81	2
	6.873 ^a	4.298 ^a	0.625 ^a		
	6.853 ^e	4.270 ^e	0.623 ^e		
Ta ₄ N ₅ <i>I4/m</i>	6.875	4.230	0.615	200.00	2
	6.831 ^a	4.269 ^a	0.624 ^a		
	6.835 ^c	4.272 ^c	0.625 ^c		
<i>Hexagonal prototypes</i>					
Nb ₅ N ₆ <i>P6₃/mcm</i>	5.335	10.603	1.987	261.349	2
	5.193 ^a	10.380 ^a	1.998 ^a		
	5.195 ^f	10.382 ^f	1.998 ^f		
Ta ₅ N ₆ <i>P6₃/mcm</i>	5.170	10.299	1.992	238.42	2
	5.181 ^b	10.361 ^b	1.999 ^b		
	5.175 ^c	10.307 ^c	1.991 ^c		
	5.160 ^d	10.270 ^d	1.990 ^d		

^a [24].

^b [25].

^c [15].

^d [16].

^e [26].

^f [27].

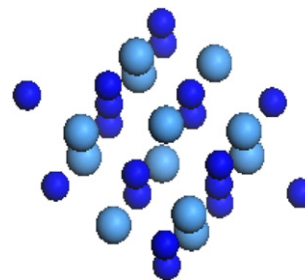


Fig. 1. M₄N₅ (M = Nb, Ta) structure: perspective view. The large and small balls represent M and N atoms.

optimization, using the Broyden-Fletcher-Goldfarb-Shanno (BFGS) minimization technique. This technique provides a fast way of finding out the lowest energy structure out of all the converged structures, with the following thresholds: energy change per atom less than 2×10^{-5} eV, residual force less than 0.05 eV/Å, displacement of atoms during the geometry optimization less than 0.002 Å, and maximum stress within 0.1 GPa. The crystal structures are reported (Table 1). The large and small balls represent M and N atoms Fig. 1.

3. Results and discussion

3.1. Structural properties

M₄N₅ (M = a transition metal (TM) Nb, Ta) compounds structures belong to the same tetragonal *I4/m* space group (No: 87, Pearson symbol *tI18*, prototype H₄Li₄Rh), with two formula units per unit cell, for Ta₄N₅ and Nb₄N₅ the compositions at.%N are 55 [14] and 15.9 [23] respectively, while M₅N₆ (M = (TM) Nb, Ta) compounds structures belong to the same hexagonal *P6₃/mcm* space group (No: 193, Pearson symbol *hP22*, prototype Nb₅N₆), with two formula units per unit cell, the composition at.%N for Ta₅N₆ and Nb₅N₆ are 54.5 [14] and 15.3 [23], M₄N₅ has 18 atoms in the unit cell, while M₅N₆ has 22 atoms as shown in Figs. 1 and 2. Results for the lattice parameter *a*, *c* and *c/a* are reported (Table 1) and compared with experimental and theoretical calculations. Our calculated GGA values for (*a*) are in rather good agreement with available experimental data [24] for M₄N₅ and M₅N₆ [24,25]. More precisely, our computed lattice constants (*a*) are bigger than the measured ones, within 5.5% and 0.6% [24] for Nb₄N₅ and Ta₄N₅ respectively, and within 2.7% [24] for Nb₅N₆ and 0.2% [25] for Ta₅N₆. Also, for both structures, the calculated lattice parameter ratio *c/a* (0.628 and 0.615 for M₄N₅ (M = (TM) Nb, Ta) respectively) is in

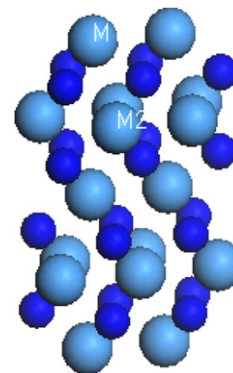


Fig. 2. M₅N₆ (M = Nb, Ta) structure: perspective view. The large and small balls represent M and N atoms.

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